- - ..

						Atty. Docket No.		Serial No.		
Form PT	0-14	49		Department o		381NP/50307				
						Applicant Nobuyasu KANEKAWA et al.				
INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)						Filing Date Group				
	e ac	Vela	ar shoots it noconsuly,			August 31, 2001				
U.S. PATENT DOCUMENTS										
Examiner Initial			Document Number		Date	Name	Class	Sub- Class	Filing Date (if appropriate)	
		AA		1						
	.,	AB			<u> </u>					
		AC			ļ			ļ		
		AD			<u> </u>					
		AE			<u> </u>					
		AF						ļ		
		AG								
		АН								
		AI			<u> </u>				,	
	}	ΑJ		, <u> </u>						
FOREIGN PATENT DOCUMENTS										
·			Document		Date	Country	Class	Sub- class	Translation Yes No	
70		AK	11-136293		5/21/99	Japan			Abstract	
· 77		AL	11-317445		11/16/99	Japan			Abstract	
		AM		<u></u>						
		AN	<u></u>	<u> </u>						
		AO	··-	1						
1		AР		<u> </u>				·		
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)										
75		QA	Artic Yamaz	le entitle aki, issue	d "Applicati d by Nikkan	ion Technique of Power MOSFET" by Hiroshi Industry Newspaper Co., pp. 55-57				
1		AR	. 1							
(AS									
EXAMINER VIII						DATE CONSIDERED 4/24/04				
EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.										